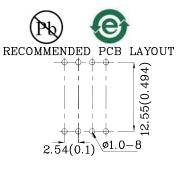
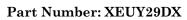


Features

- \bullet Robust package
- \bullet Uniform light disbursement
- Ideal for backlighting logos or icons
- Excellent for flush mounting
- RoHS compliant





15mmx15mm LIGHT BAR

Package Schematics □15(0.591) 8765 ORIENTATION MARK 12.55(0.494) .25(0.01) +0.25 -0.1 5(0.098)ö Ni 1 2 3 4 0.8(0.031) $11.2(0.441) 4(0.157) \pm 0.5$.5(0.098) 2 3 6 7 ¥ ¥ Ŷ $+0.25 \\ -0.1$ Ni 0.5(0.02)1 5 8 4 2.54(0.1)

Notes: 1. All dimensions are in millimeters (inches), Tolerance is ±0.25(0.01")unless otherwise noted. 2. Specifications are subject to change without notice.

Absolute Maximum Ratings (T _A =25°C)	UY (GaAsP/GaP)	Unit		
Reverse Voltage	V_{R}	5	V	
Forward Current	$\mathbf{I}_{\mathbf{F}}$	30	mA	
Forward Current (Peak) 1/10 Duty Cycle 0.1ms Pulse Width	ifs	140	mA	
Power Dissipation	\mathbf{P}_{D}	75	mW	
Operating Temperature	$T_{\rm A}$	$-40 \sim +85$	°C	
Storage Temperature	Tstg	$-40 \sim +85$		
Lead Solder Temperature [2mm Below Package Base]	260°C For 3-5 Seconds			

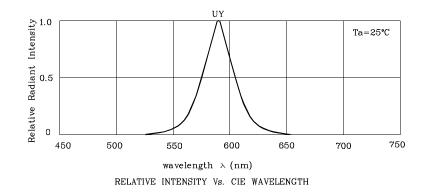
Operating Characteristics (T _A =25°C)	UY (GaAsP/GaP)	Unit	
Forward Voltage (Typ.) (I _F =10mA)	V_{F}	1.95	V
Forward Voltage (Max.) (I _F =10mA)	V_{F}	2.5	V
Reverse Current (Max.) $(V_R=5V)$	I_R	10	uA
Wavelength of Peak Emission CIE127-2007* (Typ.) (I _F =10mA)	λP	590*	nm
Wavelength of Dominant Emission CIE127-2007* (Typ.) (I _F =10mA)	λD	588*	nm
Spectral Line Full Width At Half-Maximum (Typ.) (I _F =10mA)	$ riangle\lambda$	35	nm
Capacitance (Typ.) (V _F =0V, f=1MHz)	С	20	$_{ m pF}$

_	Part Number	Emitting Color	Emitting Material	Luminous Intensity CIE127-2007* (I _F =10mA) mcd		Wavelength CIE127-2007* nm λP	Lens-color
				min.	typ.		
	XEUY29DX	Yellow	GaAsP/GaP	$21 \\ 5.6*$	34 11*	590*	Yellow Diffused

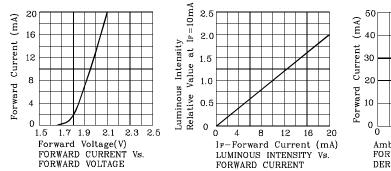
*Luminous intensity value and wavelength are in accordance with CIE127-2007 Mar 05,2014

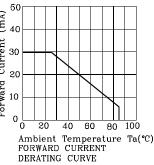
XDSA1966 V6-X Layout: Maggie L.

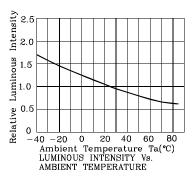




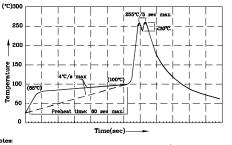
♦ UY







Wave Soldering Profile for Thru-Hole Products (Pb-Free Components)



Access I.Recommend pre-heat temperature of 105°C or less (as measured with a thermocouple attached to the LED pins) prior to immersion in the solder wave with a maximum solder bath temperature of 260°C 2.Peak wave soldering temperature between 245°C ~ 255°C for 3 sec (5 sec max)

Peak wave soldering temperature between 2400 ~ 2000 to 5 sec (o smax).
 Do not apply stress to the epoxy resin while the temperature is above
 Pixtures should not incur stress on the component when mounting and during soldering process.
 S.AG 305 solder alloy is recommended.
 No more than one wave soldering pass.

Remarks:

If special sorting is required (e.g. binning based on forward voltage,

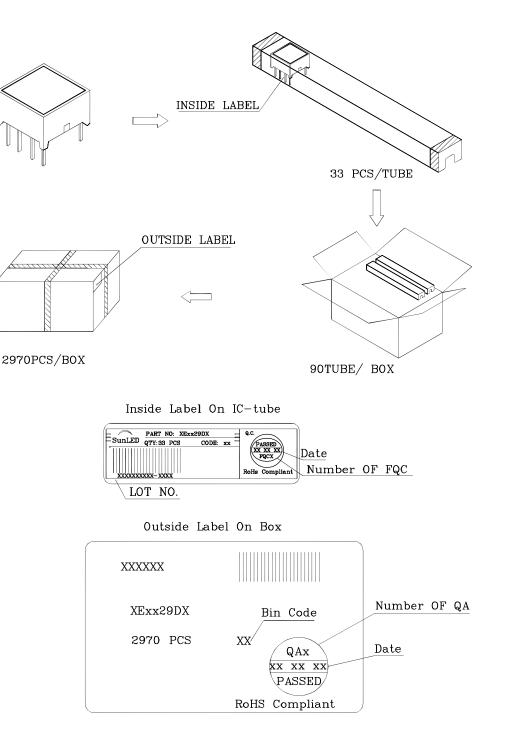
luminous intensity / luminous flux, or wavelength),

the typical accuracy of the sorting process is as follows:

- 1. Wavelength: +/-1nm
- 2. Luminous Intensity / Luminous Flux: +/-15%
- 3. Forward Voltage: +/-0.1V
- Note: Accuracy may depend on the sorting parameters.



PACKING & LABEL SPECIFICATIONS



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- 1. Data presented in this document reflect statistical figures and should be treated as technical reference only.
- 2. Contents within this document are subject to improvement and enhancement changes without notice.
- 3. The product(s) in this document are designed to be operated within the electrical and environmental specifications indicated on the datasheet.
- User accepts full risk and responsibility when operating the product(s) beyond their intended specifications.
- 4. The product(s) described in this document are intended for electronic applications in which a person's life is not reliant upon the LED. Please
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